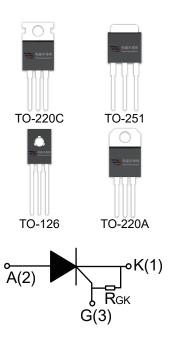


#### **DESCRIPTION:**

The X0405MF SCR series with the parallel resistor between Gate and Cathode are especially recommended for use on straight hair, igniter, anion generator, etc.

### **MAIN FEATURES**

Symbol	Value	Unit
I <sub>T(RMS)</sub>	4	Α
I <sub>GT</sub>	≤200	μA
V <sub>TM</sub>	≤1.5	V



### **ABSOLUTE MAXIMUM RATINGS**

Parameter		Symbol	Value	Unit
Storage junction temperature range		T <sub>stg</sub>	-40-150	$^{\circ}$ C
Operating junction temperature range		Tj	-40-125 <sup>1</sup>	$^{\circ}$
Repetitive pea	Repetitive peak off-state voltage		600	V
Repetitive peak reverse voltage		$V_{RRM}$	600	V
RMS on-state current	TO-220A(Non-Ins) / TO-220C(T <sub>C</sub> =110°C)			
	TO-251(Tc=90°C)	I <sub>T(RMS)</sub>	4	A
	TO-202-3/TO-126(T <sub>C</sub> =85°C)			
Non repetitive surge peak on-state current (tp=10ms)		Ітѕм	30	А
I <sup>2</sup> t value for fusing (tp=10ms)		l <sup>2</sup> t	4.5	$A^2s$
Critical rate of rise of on-state current		dI/dt	50	A/µs
Peak gate current (tp=20µs, T <sub>j</sub> =125℃)		I <sub>GM</sub>	1.2	Α
Peak gate power (tp=20µs, T <sub>j</sub> =125℃)		P <sub>GM</sub>	2	W
Average gate power dissipation(T <sub>j</sub> =125℃)		P <sub>G(AV)</sub>	0.2	W

**NOTE 1:** When we parallel connect a  $\leq 1K\Omega$  resistor between Gate and Cathode, the Tj can reach 125°C; if without this resistor, the Tj only can reach 110°C.



# **ELECTRICAL CHARACTERISTICS** ( $T_j$ =25 $^{\circ}$ C unless otherwise specified)

Symbol	Test Condition	Value			Unit
Symbol	rest Condition	MIN.	TYP.	MAX.	Offic
lgт	V <sub>D</sub> =12V R <sub>L</sub> =33Ω	-	50	200	μA
V <sub>G</sub> T	VD-12V KL-3312	-	0.6	0.8	V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =125℃	0.2	1	-	V
IL	I <sub>G</sub> =1.2 I <sub>GT</sub>	-	-	6	mA
Ін	I <sub>T</sub> =0.05A	-	1	5	mA
dV/dt	$V_D=2/3V_{DRM}$ $T_j=125$ °C $R_{GK}=1K\Omega$	10	-	-	V/µs

## **STATIC CHARACTERISTICS**

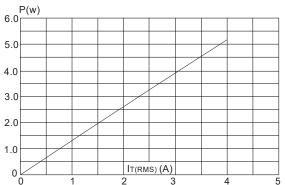
Symbol	Parameter		Value(MAX)	Unit
V <sub>TM</sub>	I <sub>TM</sub> =8A tp=380μs	T <sub>j</sub> =25℃	1.5	V
I <sub>DRM</sub>	VD=VDRM VR=VRRM	T <sub>j</sub> =25℃	5	μA
I <sub>RRM</sub>		T <sub>j</sub> =125℃	200	μA

## **THERMAL RESISTANCES**

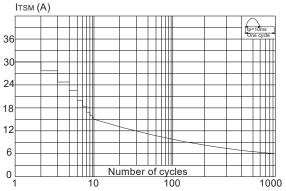
Symbol	Parameter		Value	Unit
Rth(j-c)	junction to case	TO-220A(Non-Ins)/ TO-220C	2.8	°C/W
		TO-251	6.5	
		TO-202-3/ TO-126	7.2	



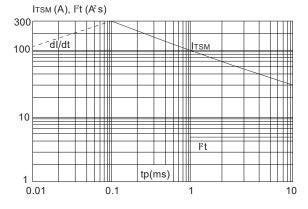
**FIG.1:** Maximum power dissipation versus RMS on-state current



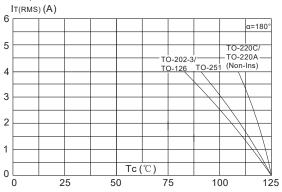
**FIG.3:** Surge peak on-state current versus number of cycles



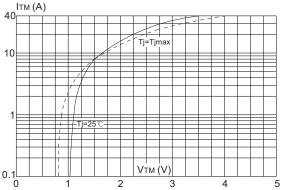
**FIG.5:** Non-repetitive surge peak on-state current for a sinusoidal pulse with width tp<10ms, and corresponging value of l²t (dl/dt < 50A/μs)



**FIG.2:** RMS on-state current versus case temperature



**FIG.4:** On-state characteristics (maximum values)



**FIG.6:** Relative variations of gate trigger current, holding current and latching current versus junction temperature

